



#### 80V NPN MEDIUM POWER TRANSISTOR IN PowerDI3333-8

#### **Features**

- BVcEo > 80V
- Small Form Factor Thermally Efficient Package.
   Enables Higher Density End Products
- I<sub>C</sub> = 1A Continuous Collector Current
- Icm = 2A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 500mV @ 0.5A</li>
- Complementary PNP Types: DXTP06080BFG
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic. "Green" Molding Compound;
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

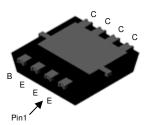
#### **Applications**

- Medium Power Switching
- Power Amplification
- AF Driver and Output Stages

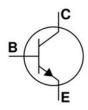
PowerDI3333-8 (SWP) (Type UX)







**Bottom View** 



Device Symbol

### **Ordering Information** (Note 4)

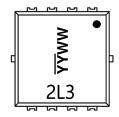
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	<b>Quantity Per Reel</b>
DXTN06080BFG-7	Standard	2L3	7	12	2,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Hallogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

PowerDI3333-8 (SWP) (Type UX)



2L3= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 21 = 2021)

WW = Week Code (01 to 53)



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	80	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Collector Current	Ісм	2	Α
Continuous Base Current	IB	100	mA
Peak Pulse Base Current	Івм	200	mA

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	Б	1	W
Power dissipation	(Note 6)	P <sub>D</sub>	2.1	W
Thormal Posistance, Junction to Ambient	(Note 5)	D	128	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	59	°C/W
Thermal Resistance, Junction to Leads (Note 7)		Rejl	10.7	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

### ESD Ratings (Note 8)

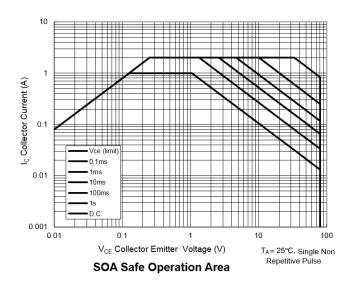
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

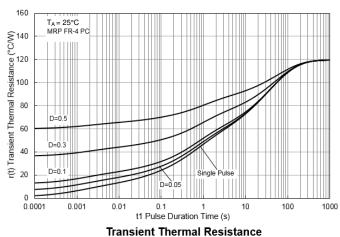
Notes:

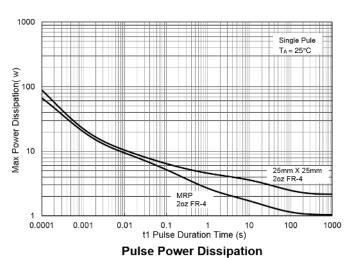
- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
  6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
  7. Thermal resistance from junction to solder-point (at the collector tab).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

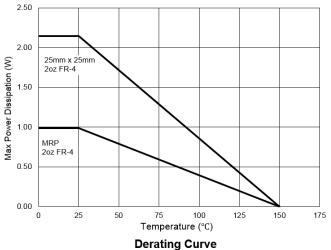


### **Thermal Characteristics and Derating Information**











### **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

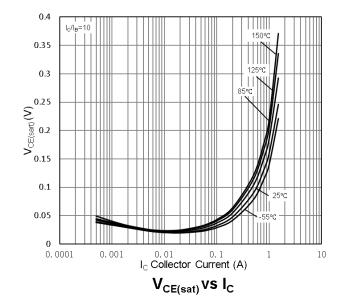
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	300	_	V	$I_C = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	80	139	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	_	V	I <sub>E</sub> = 100μA
Collector-Base Cut-Off Current	I <sub>CBO</sub>	_	8 0.1	50 20	nA μA	$V_{CB} = 100V$ $V_{CB} = 80V$ , $T_A = +150$ °C
Collector-Emitter Cut-Off Current	I <sub>CES</sub>	_	6	20	nΑ	$V_{CE} = 80V$
Emitter Cut-Off Current	I <sub>EBO</sub>		0.1	20	nA	$V_{EB} = 6V$
Static Forward Current Transfer Ratio (Note 9)	h <sub>FE</sub>	25 100 40 25 —	129 127 60 36 28	250 — — —	_	$\begin{split} I_C &= 5mA, \ V_{CE} = 2V \\ I_C &= 150mA, \ V_{CE} = 2V \\ I_C &= 500mA, \ V_{CE} = 2V \\ I_C &= 800mA, \ V_{CE} = 2V \\ I_C &= 1A, \ V_{CE} = 2V \\ I_C &= 1A, \ V_{CE} = 2V \end{split}$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	91 135	250 500	mV	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$ $I_C = 800 \text{mA}, I_B = 50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	_	0.821	1	V	$I_{C} = 500 \text{mA}, V_{CE} = 2V$
Input Capacitance	$C_{ibo}$	_	160	_	pF	$V_{EB} = 0.5V$ . $f = 1MHz$
Output Capacitance	$C_{obo}$	_	11	_	pF	$V_{CB} = 10V. f = 1MHz$
Transition Frequency	f⊤		130	_	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}$ f = 100MHz
	t <sub>delay</sub>	_	8.6	_	ns	
Switching Characteristics	t <sub>rise</sub>	_	3.8	_	ns	$V_{CC} = -10V, I_{C} = 500mA$
Owntoming Orial acteristics	$t_{storage}$	_	491	_	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$
	$t_{fall}$	_	171	_	ns	

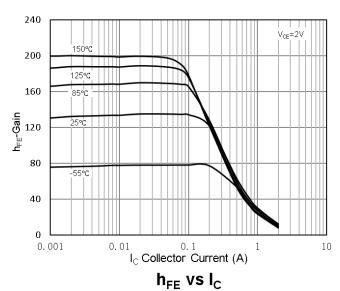
Note:

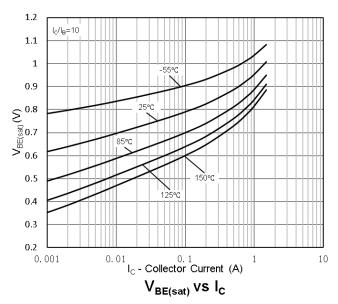
9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

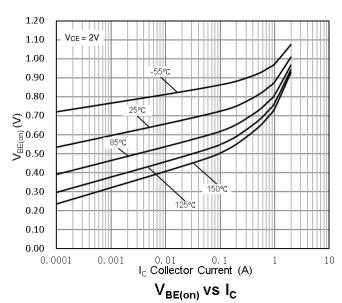


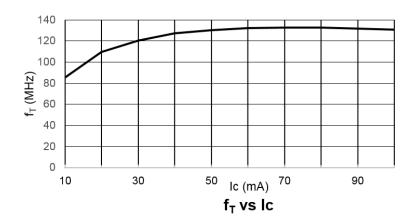
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









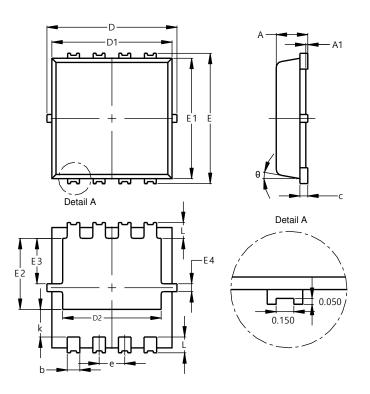




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)

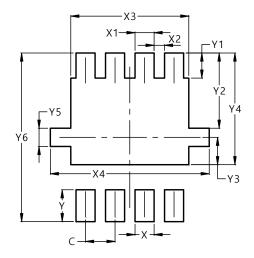


PowerDI3333-8 (SWP)						
	(Type UX)					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	-			
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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